

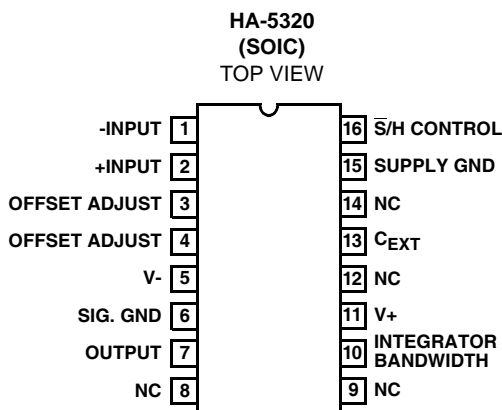
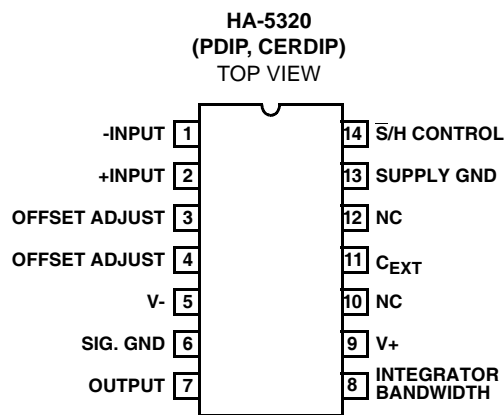
1 Microsecond Precision Sample and Hold Amplifier

The HA-5320 was designed for use in precision, high speed data acquisition systems.

The circuit consists of an input transconductance amplifier capable of providing large amounts of charging current, a low leakage analog switch, and an output integrating amplifier. The analog switch sees virtual ground as its load; therefore, charge injection on the hold capacitor is constant over the entire input/output voltage range. The pedestal voltage resulting from this charge injection can be adjusted to zero by use of the offset adjust inputs. The device includes a hold capacitor. However, if improved droop rate is required at the expense of acquisition time, additional hold capacitance may be added externally.

This monolithic device is manufactured using the Intersil Dielectric Isolation Process, minimizing stray capacitance and eliminating SCRs. This allows higher speed and latch-free operation. For further information, please see Application Note AN538.

Pinouts



Features

- Gain, DC 2×10^6 V/V
- Acquisition Time 1.0μs (0.01%)
- Droop Rate 0.08μV/μs (25°C)
17μV/μs (Full Temperature)
- Aperture Time 25ns
- Hold Step Error (See Glossary) 5mV
- Internal Hold Capacitor
- Fully Differential Input
- TTL Compatible
- Pb-Free Plus Anneal Available (RoHS Compliant)

Applications

- Precision Data Acquisition Systems
- Digital to Analog Converter Deglitcher
- Auto Zero Circuits
- Peak Detector

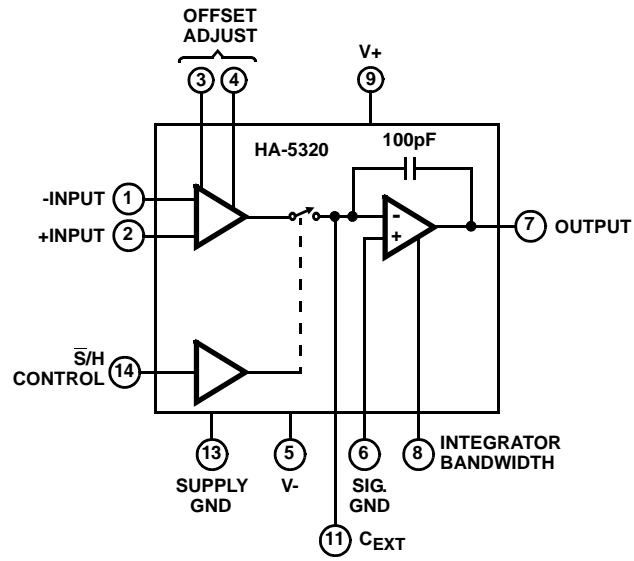
Ordering Information

PART NUMBER	PART MARKING	TEMP. RANGE (°C)	PACKAGE	PKG. DWG. #
HA1-5320-2	HA1-5320-2	-55 to +125	14 Ld Cerdip	F14.3
HA1-5320-5	HA1-5320-5	0 to +75	14 Ld Cerdip	F14.3
HA3-5320-5	HA3-5320-5	0 to +75	14 Ld PDIP	E14.3
HA9P5320-5	HA9P5320-5	0 to +75	16 Ld SOIC	M16.3
HA9P5320-5Z (Note)	HA9P5320-5Z	0 to +75	16 Ld SOIC (Pb-free)	M16.3

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

HA-5320

Functional Diagram



HA-5320

Absolute Maximum Ratings

Supply Voltage	.40V
Differential Input Voltage	.24V
Digital Input Voltage	+8V, -15V
Output Current, Continuous (Note 1)	±20mA

Operating Conditions

Temperature Range	
HA-5320-2	-55°C to 125°C
HA-5320-5	0°C to 75°C
Supply Voltage Range (Typical, Note 2)	±13.5V to ±20V

Thermal Information

Thermal Resistance (Typical, Note 3)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
CERDIP Package	70	18
PDIP Package	75	N/A
SOIC Package	90	N/A
Maximum Junction Temperature (Ceramic Package)	175°C	
Maximum Junction Temperature (Plastic Package)	150°C	
Maximum Storage Temperature Range	-65°C to 150°C	
Maximum Lead Temperature (Soldering 10s)	300°C (SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

1. Internal Power Dissipation may limit Output Current below 20mA.
2. Specification based on a one time characterization. This parameter is not guaranteed.
3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications

$V_{SUPPLY} = \pm 15.0V$; $C_H = \text{Internal}$; Digital Input: $V_{IL} = +0.8V$ (Sample), $V_{IH} = +2.0V$ (Hold), Unity Gain Configuration (Output tied to -Input), Unless Otherwise Specified

PARAMETER	TEST CONDITIONS	TEMP. (°C)	HA-5320-2			HA-5320-5			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
INPUT CHARACTERISTICS									
Input Voltage Range		Full	±10	-	-	±10	-	-	V
Input Resistance		25	1	5	-	1	5	-	MΩ
Input Capacitance		25	-	-	5	-	-	5	pF
Offset Voltage		25	-	0.2	-	-	0.5	-	mV
		Full	-	-	2.0	-	-	1.5	mV
Bias Current		25	-	70	200	-	100	300	nA
		Full	-	-	200	-	-	300	nA
Offset Current		25	-	30	100	-	30	300	nA
		Full	-	-	100	-	-	300	nA
Common Mode Range		Full	±10	-	-	±10	-	-	V
CMRR	$V_{CM} = \pm 5V$	25	80	90	-	72	90	-	dB
Offset Voltage Temperature Coefficient		Full	-	5	15	-	5	20	μV/°C
TRANSFER CHARACTERISTICS									
Gain	DC, (Note 12)	25	10^6	2×10^6	-	3×10^5	2×10^6	-	V/V
Gain Bandwidth Product ($A_V = +1$, Note 5)	$C_H = 100pF$	25	-	2.0	-	-	2.0	-	MHz
	$C_H = 1000pF$	25	-	0.18	-	-	0.18	-	MHz
OUTPUT CHARACTERISTICS									
Output Voltage		Full	±10	-	-	±10	-	-	V
Output Current		25	±10	-	-	±10	-	-	mA
Full Power Bandwidth	Note 4	25	-	600	-	-	600	-	kHz
Output Resistance	Hold Mode	25	-	1.0	-	-	1.0	-	Ω
Total Output Noise (DC to 10MHz)	Sample	25	-	125	200	-	125	200	μV _{RMS}
	Hold	25	-	125	200	-	125	200	μV _{RMS}

HA-5320

Electrical Specifications $V_{SUPPLY} = \pm 15.0V$; $C_H = \text{Internal}$; Digital Input: $V_{IL} = +0.8V$ (Sample), $V_{IH} = +2.0V$ (Hold), Unity Gain Configuration (Output tied to -Input), Unless Otherwise Specified **(Continued)**

PARAMETER	TEST CONDITIONS	TEMP. (°C)	HA-5320-2			HA-5320-5			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
TRANSIENT RESPONSE									
Rise Time	Note 5	25	-	100	-	-	100	-	ns
Overshoot	Note 5	25	-	15	-	-	15	-	%
Slew Rate	Note 6	25	-	45	-	-	45	-	V/ μ s
DIGITAL INPUT CHARACTERISTICS									
Input Voltage	V_{IH}	Full	2.0	-	-	2.0	-	-	V
	V_{IL}	Full	-	-	0.8	-	-	0.8	V
Input Current	$V_{IL} = 0V$	25	-	-	4	-	-	4	μ A
		Full	-	-	10	-	-	10	μ A
	$V_{IH} = +5V$	Full	-	-	0.1	-	-	0.1	μ A
SAMPLE AND HOLD CHARACTERISTICS									
Acquisition Time (Note 7)	To 0.1%	25	-	0.8	1.2	-	0.8	1.2	μ s
	To 0.01%	25	-	1.0	1.5	-	1.0	1.5	μ s
Aperture Time (Note 8)		25	-	25	-	-	25	-	ns
Effective Aperture Delay Time		25	-50	-25	0	-50	-25	0	ns
Aperture Uncertainty		25	-	0.3	-	-	0.3	-	ns
Droop Rate		25	-	0.08	0.5	-	0.08	0.5	μ V/ μ s
		Full	-	17	100	-	1.2	100	μ V/ μ s
Drift Current	Note 9	25	-	8	50	-	8	50	pA
		Full	-	1.7	10	-	0.12	10	nA
Charge Transfer	Note 9	25	-	0.5	1.1	-	0.5	1.1	pC
Hold Step Error	Note 9	25	-	5	11	-	5	11	mV
Hold Mode Settling Time	To 0.01%	Full	-	165	350	-	165	350	ns
Hold Mode Feedthrough	10V _{P-P} , 100kHz	Full	-	2	-	-	2	-	mV
POWER SUPPLY CHARACTERISTICS									
Positive Supply Current	Note 10	25	-	11	13	-	11	13	mA
Negative Supply Current	Note 10	25	-	-11	-13	-	-11	-13	mA
Supply Voltage Range	Note 2		± 13.5	-	± 20	± 13.5	-	± 20	V
Power Supply Rejection	V_+ , Note 11	Full	80	-	-	80	-	-	dB
	V_- , Note 11	Full	65	-	-	65	-	-	dB

NOTES:

4. $V_O = 20V_{P-P}$; $R_L = 2k\Omega$; $C_L = 50pF$; unattenuated output.
5. $V_O = 200mV_{P-P}$; $R_L = 2k\Omega$; $C_L = 50pF$.
6. $V_O = 20V$ Step; $R_L = 2k\Omega$; $C_L = 50pF$.
7. $V_O = 10V$ Step; $R_L = 2k\Omega$; $C_L = 50pF$.
8. Derived from computer simulation only; not tested.
9. $V_{IN} = 0V$, $V_{IH} = +3.5V$, $t_R < 20ns$ (V_{IL} to V_{IH}).
10. Specified for a zero differential input voltage between +IN and -IN. Supply current will increase with differential input (as may occur in the Hold mode) to approximately $\pm 46mA$ at 20V.
11. Based on a 1V delta in each supply, i.e. $15V \pm 0.5V_{DC}$.
12. $R_L = 1k\Omega$, $C_L = 30pF$.

Test Circuits and Waveforms

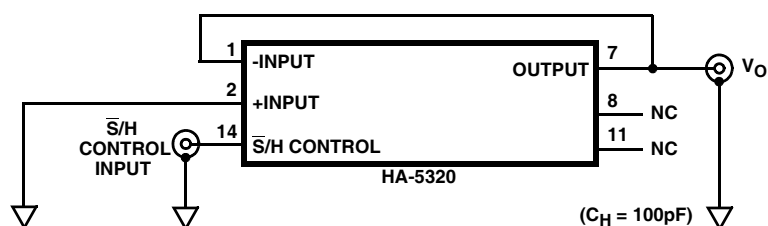
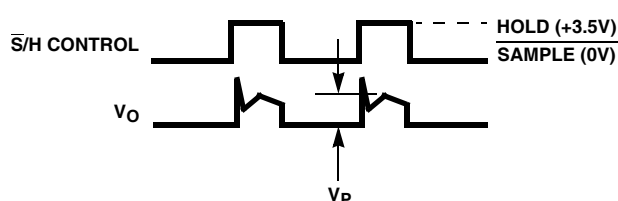


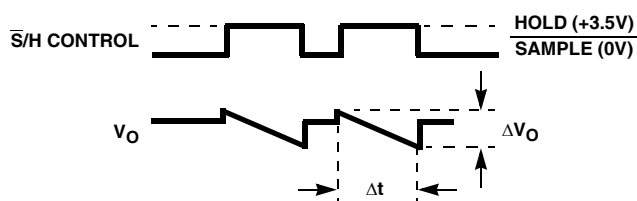
FIGURE 1. CHARGE TRANSFER AND DRIFT CURRENT



NOTES:

13. Observe the “hold step” voltage V_P .
14. Compute charge transfer: $Q = V_P C_H$.

FIGURE 2. CHARGE TRANSFER TEST



NOTES:

15. Observe the voltage “droop”, $\Delta V_O / \Delta t$.
16. Measure the slope of the output during hold, $\Delta V_O / \Delta t$, and compute drift current: $I_D = C_H \Delta V_O / \Delta t$.

FIGURE 3. DRIFT CURRENT TEST

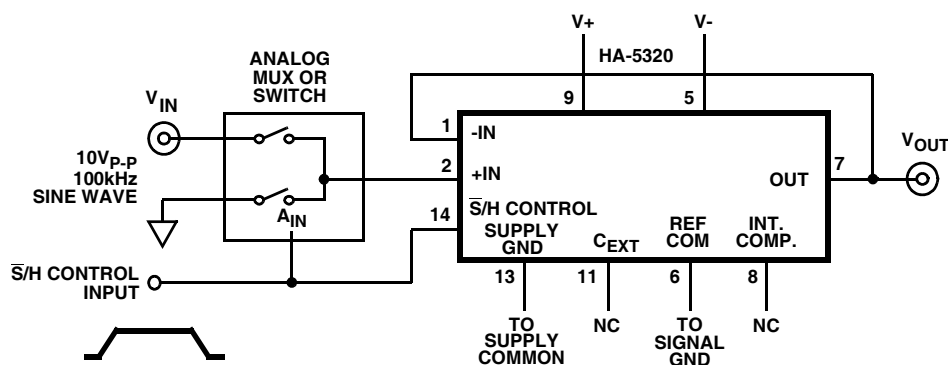


FIGURE 4. HOLD MODE FEEDTHROUGH ATTENUATION

NOTE:

Feedthrough in

$$\text{dB} = 20 \log \frac{V_{\text{OUT}}}{V_{\text{IN}}} \quad \text{where:}$$

$$V_{\text{OUT}} = V_{P-P, \text{ Hold Mode}}, V_{\text{IN}} = V_{P-P}$$

Application Information

The HA-5320 has the uncommitted differential inputs of an op amp, allowing the Sample and Hold function to be combined with many conventional op amp circuits. See the Intersil Application Note AN517 for a collection of circuit ideas.

Layout

A printed circuit board with ground plane is recommended for best performance. Bypass capacitors (0.01 μ F to 0.1 μ F, ceramic) should be provided from each power supply terminal to the Supply Ground terminal on pin 13.

The ideal ground connections are pin 6 (SIG. Ground) directly to the system Signal Ground, and pin 13 (Supply Ground) directly to the system Supply Common.

Hold Capacitor

The HA-5320 includes a 100pF MOS hold capacitor, sufficient for most high speed applications (the Electrical Specifications section is based on this internal capacitor).

Additional capacitance may be added between pins 7 and 11. This external hold capacitance will reduce droop rate at the expense of acquisition time, and provide other trade-offs as shown in the Performance Curves.

If an external hold capacitor C_{EXT} is used, then a noise bandwidth capacitor of value 0.1 C_{EXT} should be connected from pin 8 to ground. Exact value and type are not critical.

The hold capacitor C_{EXT} should have high insulation resistance and low dielectric absorption, to minimize droop errors. Polystyrene dielectric is a good choice for operating temperatures up to 85°C. Teflon® and glass dielectrics offer good performance to 125°C and above.

Typical Performance Curves

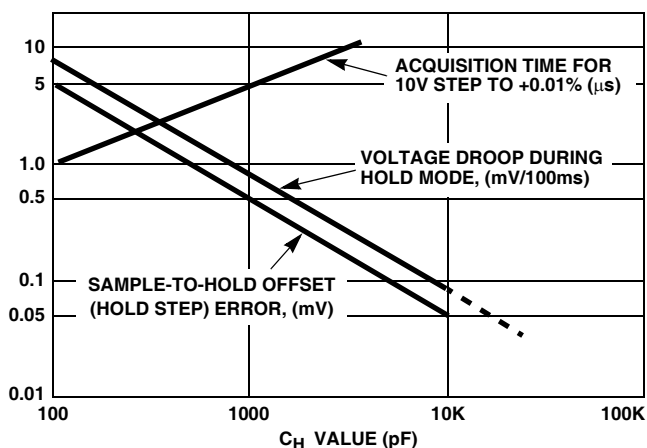


FIGURE 6. TYPICAL SAMPLE AND HOLD PERFORMANCE AS A FUNCTION OF HOLD CAPACITOR

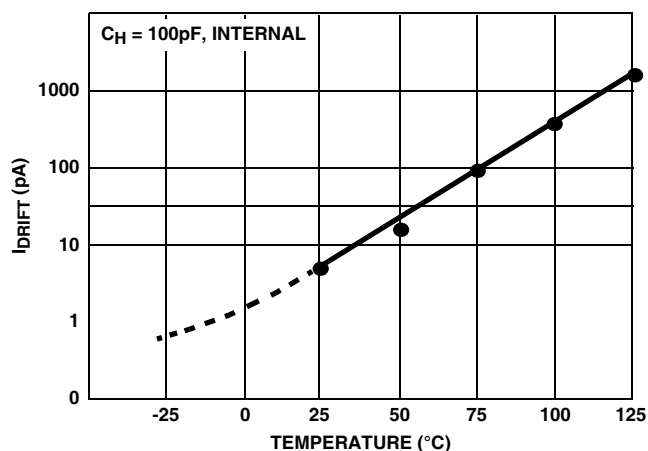


FIGURE 7. DRIFT CURRENT vs TEMPERATURE

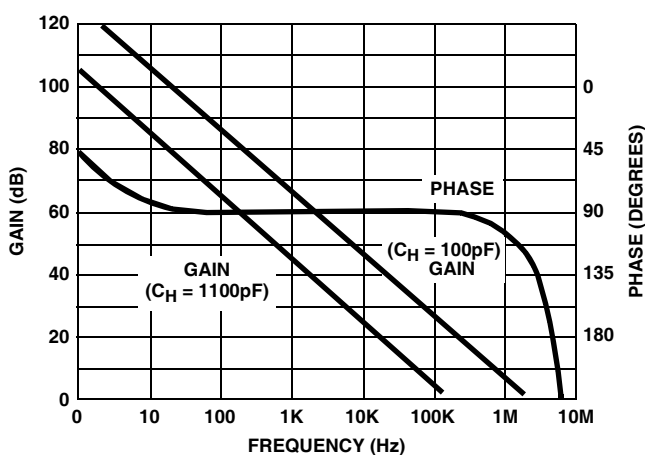


FIGURE 8. OPEN LOOP GAIN AND PHASE RESPONSE

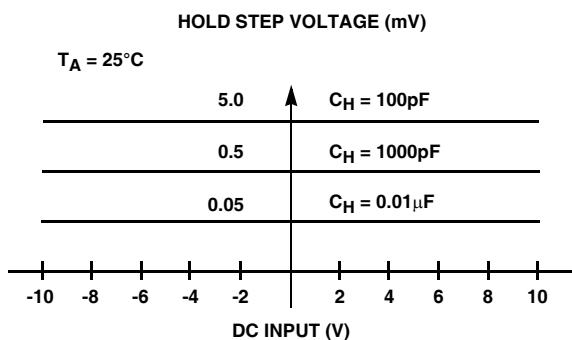


FIGURE 9A. HOLD STEP vs INPUT VOLTAGE

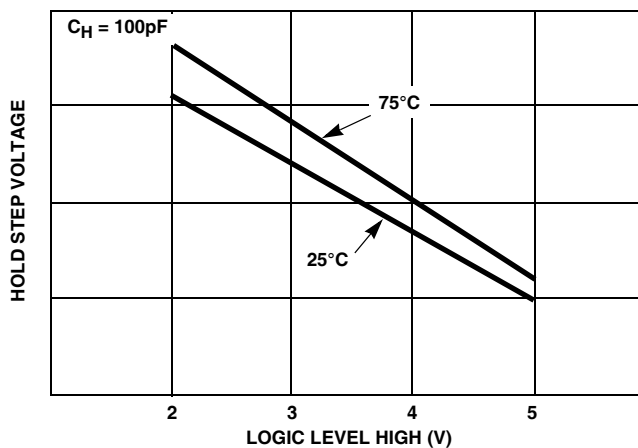


FIGURE 9B. HOLD STEP vs LOGIC (V_{IH}) VOLTAGE

FIGURE 9. TYPICAL SAMPLE-TO-HOLD OFFSET (HOLD STEP) ERROR

HA-5320

Die Characteristics

DIE DIMENSIONS:

92 mils x 152 mils x 19 mils

METALLIZATION:

Type: Al, 1% Cu
Thickness: $16\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$

PASSIVATION:

Type: Nitride (Si_3N_4) over Silox (SiO_2 , 5% Phos)
Silox Thickness: $12\text{k}\text{\AA} \pm 2\text{k}\text{\AA}$
Nitride Thickness: $3.5\text{k}\text{\AA} \pm 1.5\text{k}\text{\AA}$

TRANSISTOR COUNT:

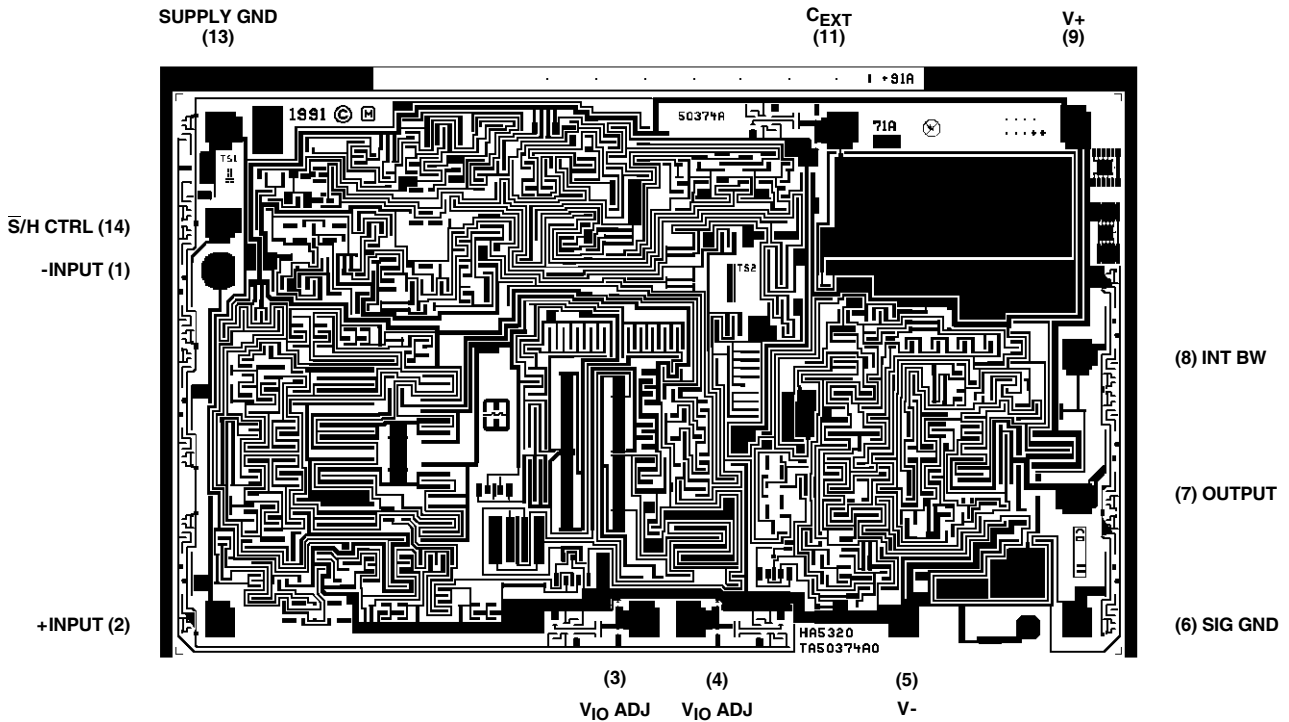
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SUBSTRATE POTENTIAL:

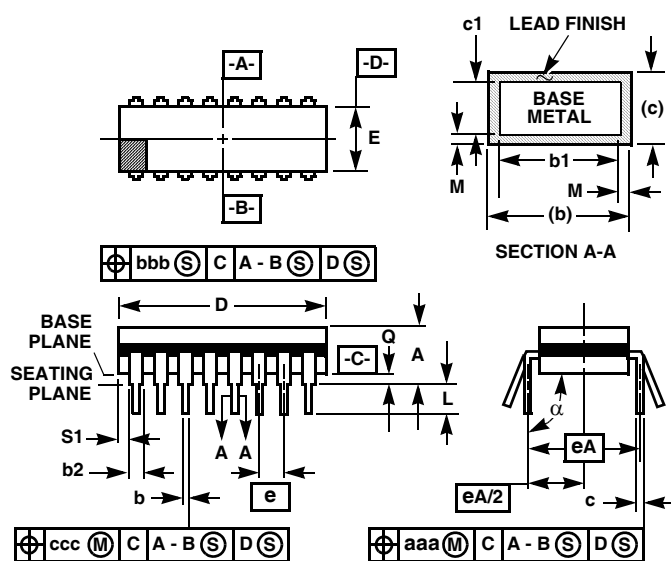
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Metallization Mask Layout

HA-5320



Ceramic Dual-In-Line Frit Seal Packages (CERDIP)



NOTES:

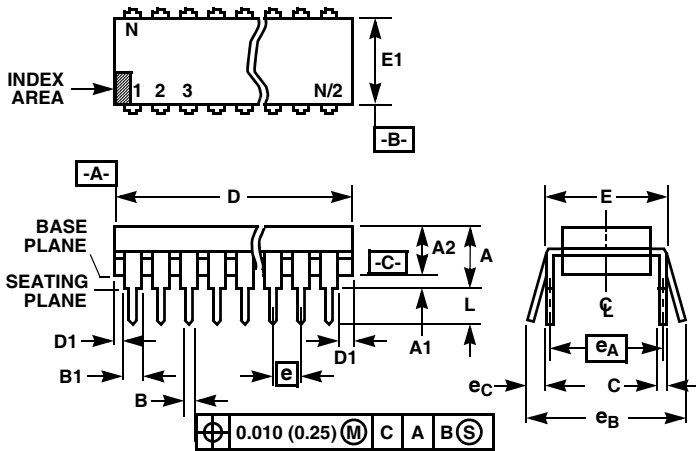
1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
5. This dimension allows for off-center lid, meniscus, and glass overrun.
6. Dimension Q shall be measured from the seating plane to the base plane.
7. Measure dimension S1 at all four corners.
8. N is the maximum number of terminal positions.
9. Dimensioning and tolerancing per ANSI Y14.5M - 1982.
10. Controlling dimension: INCH.

F14.3 MIL-STD-1835 GDIP1-T14 (D-1, CONFIGURATION A)
14 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.200	-	5.08	-
b	0.014	0.026	0.36	0.66	2
b1	0.014	0.023	0.36	0.58	3
b2	0.045	0.065	1.14	1.65	-
b3	0.023	0.045	0.58	1.14	4
c	0.008	0.018	0.20	0.46	2
c1	0.008	0.015	0.20	0.38	3
D	-	0.785	-	19.94	5
E	0.220	0.310	5.59	7.87	5
e	0.100 BSC		2.54 BSC		-
eA	0.300 BSC		7.62 BSC		-
eA/2	0.150 BSC		3.81 BSC		-
L	0.125	0.200	3.18	5.08	-
Q	0.015	0.060	0.38	1.52	6
S1	0.005	-	0.13	-	7
alpha	90°	105°	90°	105°	-
aaa	-	0.015	-	0.38	-
bbb	-	0.030	-	0.76	-
ccc	-	0.010	-	0.25	-
M	-	0.0015	-	0.038	2, 3
N	14		14		8

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Dual-In-Line Plastic Packages (PDIP)



NOTES:

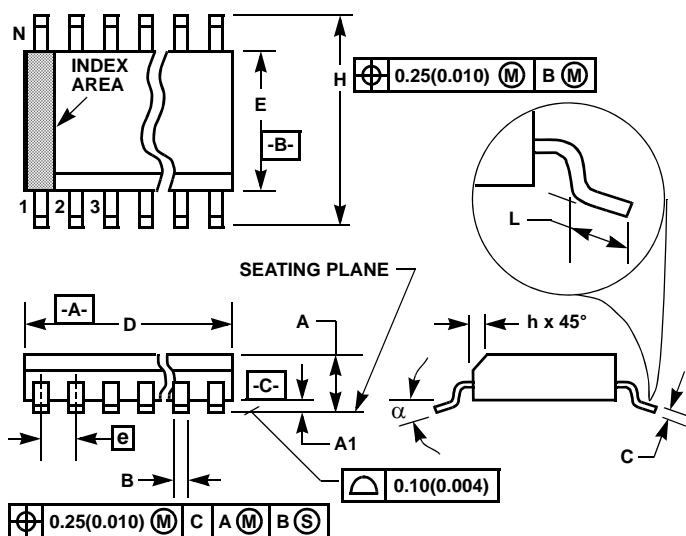
- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- E and e_A are measured with the leads constrained to be perpendicular to datum $-C-$.
- e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E14.3 (JEDEC MS-001-AA ISSUE D)
14 LEAD DUAL-IN-LINE PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	-	0.210	-	5.33	4
A1	0.015	-	0.39	-	4
A2	0.115	0.195	2.93	4.95	-
B	0.014	0.022	0.356	0.558	-
B1	0.045	0.070	1.15	1.77	8
C	0.008	0.014	0.204	0.355	-
D	0.735	0.775	18.66	19.68	5
D1	0.005	-	0.13	-	5
E	0.300	0.325	7.62	8.25	6
E1	0.240	0.280	6.10	7.11	5
e	0.100 BSC		2.54 BSC		-
e_A	0.300 BSC		7.62 BSC		6
e_B	-	0.430	-	10.92	7
L	0.115	0.150	2.93	3.81	4
N	14		14		9

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Small Outline Plastic Packages (SOIC)



**M16.3 (JEDEC MS-013-AA ISSUE C)
16 LEAD WIDE BODY SMALL OUTLINE PLASTIC PACKAGE**

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.0926	0.1043	2.35	2.65	-
A1	0.0040	0.0118	0.10	0.30	-
B	0.013	0.0200	0.33	0.51	9
C	0.0091	0.0125	0.23	0.32	-
D	0.3977	0.4133	10.10	10.50	3
E	0.2914	0.2992	7.40	7.60	4
e	0.050 BSC		1.27 BSC		-
H	0.394	0.419	10.00	10.65	-
h	0.010	0.029	0.25	0.75	5
L	0.016	0.050	0.40	1.27	6
N	16		16		7
alpha	0°	8°	0°	8°	-

NOTES:

1. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
3. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
6. "L" is the length of terminal for soldering to a substrate.
7. "N" is the number of terminal positions.
8. Terminal numbers are shown for reference only.
9. The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch)
10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

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